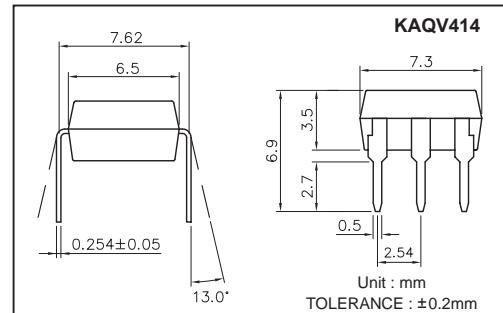


Features

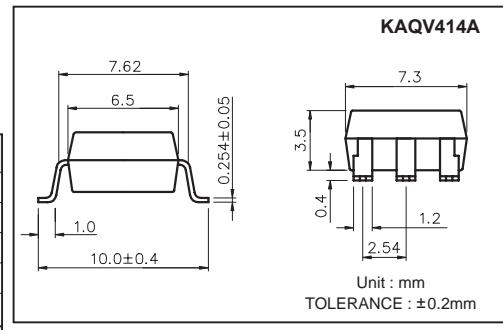
1. Normally Close, Single Pole Single Throw
2. Control 400VAC or DC Voltage
3. Switch 130mA Loads
4. LED control Current, 5mA
5. Low ON-Resistance
6. dv/dt, >500V/ms
7. Isolation Test Voltage, 3750VACrms



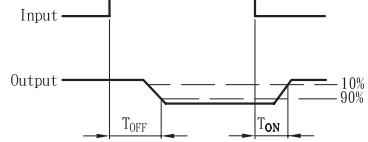
Absolute Maximum Ratings

(Ta=25°C)

| Emitter (Input) | Detector (Output) |
|--|--|
| Reverse Voltage.....5.0V | Output Breakdown Voltage±400V |
| Continuous Forward Current50mA | Continuous Load Current±130mA |
| Peak Forward Current1A | Power Dissipation500mW |
| Power Dissipation100mW | |
| Derate Linearly from 25°C1.3mW/°C | |
| General Characteristics | |
| Isolation Test Voltage.....3750VACrms | Storage Temperature Range ...-40°C to +125°C |
| Isolation Resistance | Operating Temperature Range...-30°C to +85°C |
| Vio=500V, Ta=25°C≥10 ¹⁰ Ω | Junction Temperature.....100°C |
| Total Power Dissipation550mW | Soldering Temperature, |
| Derate Linearly from 25°C2.5mW/°C | 2mm from case, 10 sec260°C |



Operate/ Reverse time

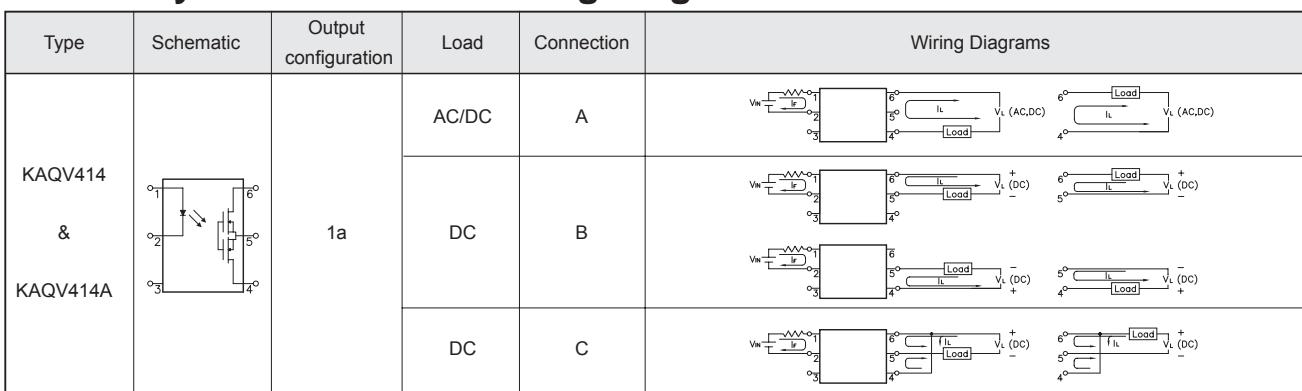


Electro-optical Characteristics

(Ta=25°C)

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit | | |
|--------------------------|------------------|---|---|--|------|--------|--|--|
| Emitter (Input) | | | | | | | | |
| Forward Voltage | VF | IF = 10mA | | 1.2 | 1.5 | V | | |
| Operation Input Current | I _{OFF} | V _L = ±20V, I _L ≤ 5μA | | | 5 | mA | | |
| Recovery Input Current | I _{ON} | V _L = ±20V, I _L = 100mA, t = 10ms | 0.2 | | | mA | | |
| Detector (Output) | | | | | | | | |
| Output Breakdown Voltage | V _B | I _B = 50μA | 400 | | | V | | |
| Output Off-State Leakage | I _{OFF} | V _T = 100V, I _F = 10mA | | 0.2 | 2 | uA | | |
| I/O Capacitance | C _{ISO} | I _F = 0, f = 1MHz | | 6 | | pF | | |
| ON Resistance | Connection | A B C | I _L = 100mA, I _F = 10mA | 40 | 50 | Ω | | |
| | | | | 20 | 25 | | | |
| | | | | 10 | 12.5 | | | |
| Reverse (ON) Time | | | T _{ON} | I _F = 10mA, V _L = ±20V | 0.6 | 1.5 ms | | |
| Operate (OFF) Time | | | T _{OFF} | t = 10ms, I _L = ±100mA | 0.3 | 1.0 ms | | |

Mos Relay Schematic and Wiring Diagrams



Data Curve

Fig.1 Load current vs. ambient temperature
Allowable ambient temperature:
-40°C to +85°C

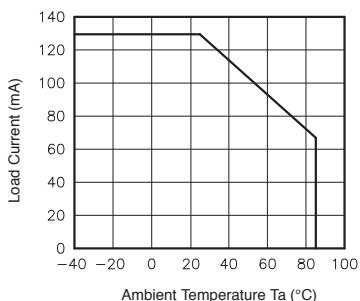


Fig.2 On resistance vs. ambient temperature
Across terminals 4 and 6 pin
LED current: 0mA
Continuous load current: 130mA(DC)

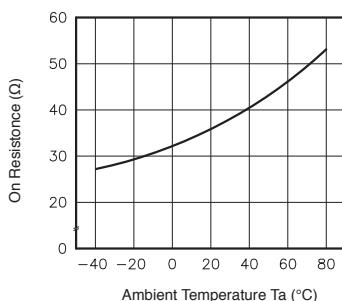


Fig.3 Operate (OFF) time vs. ambient temperature
Load voltage 400V(DC)
LED current: 5mA
Continuous load current: 130mA(DC)

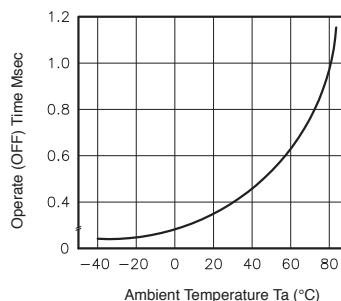


Fig.4 Reverse (NO) time vs. ambient temperature
LED current: 5mA;
Load voltage: 400V(DC); Continuous load current: 130mA(DC)

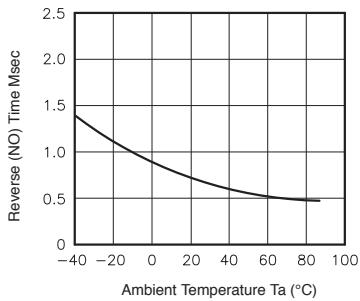


Fig.5 LED operate (OFF) vs. ambient temperature
Load voltage: 400V(DC); Continuous load current: 130mA(DC)

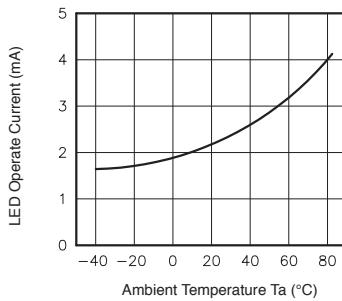


Fig.6 LED reverse (NO) current vs. ambient temperature
Load voltage: 400V(DC)
Continuous load current: 130mA(DC)

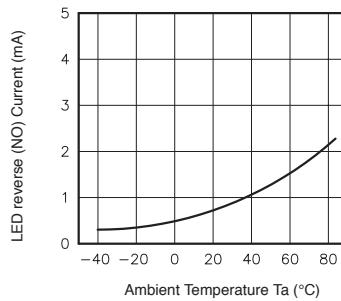


Fig.7 LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA

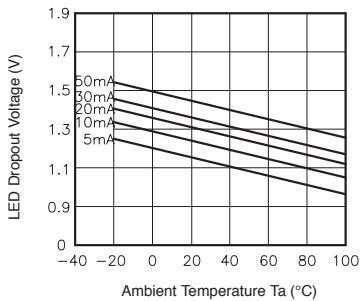


Fig.8 Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 4 and 6 pin
Ambient temperature: 25°C

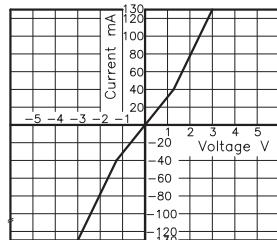


Fig.9 Off state leakage current
Across terminals 4 and 6 pin
Ambient temperature: 25°C

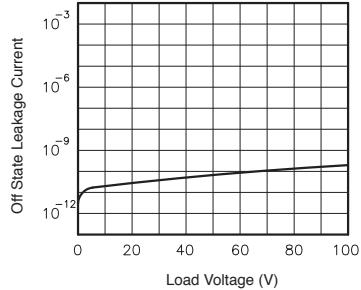


Fig.10 LED forward current vs. operate (OFF) time
Across terminals 4 and 6 pin;
Load voltage: 400V (DC);
Continuous load current: 130mA (DC);
Ambient temperature: 25°C

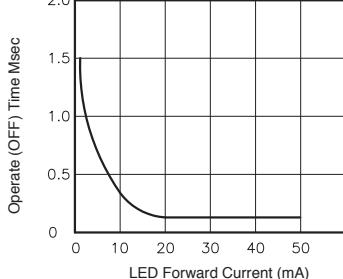


Fig.11 LED forward current vs. reverse (NO) time
Across terminals 4 and 6 pin;
Load voltage: 400V (DC);
Continuous load current: 130mA (DC);
Ambient temperature: 25°C

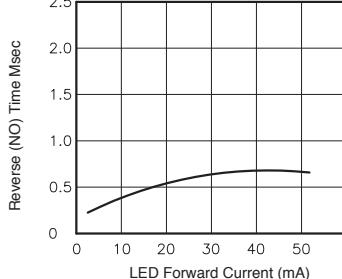


Fig.12 Applied voltage vs. output capacitance
Across terminals 4 and 6 pin
Frequency: 1MHz
Ambient temperature: 25°C

